

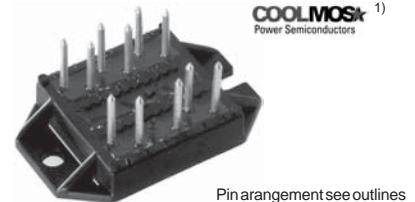
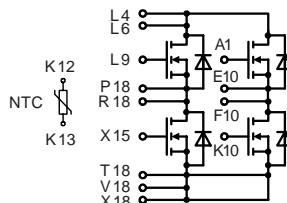
# CoolMOS Power MOSFET

## in ECO-PAC 2

N-Channel Enhancement Mode  
Low  $R_{DSon}$ , High  $V_{DSS}$  MOSFET  
Package with Electrically Isolated Base

Preliminary data sheet

$I_{D25} = 38 \text{ A}$   
 $V_{DSS} = 600 \text{ V}$   
 $R_{DSon} = 70 \text{ m}\Omega$



COOLMOS<sup>®</sup>  
Power Semiconductors

Pin arrangement see outlines

### MOSFET

Symbol	Conditions	Maximum Ratings		
$V_{DSS}$	$T_{VJ} = 25^\circ\text{C}$ to $150^\circ\text{C}$	600		V
$V_{GS}$		$\pm 20$		V
$I_{D25}$	$T_c = 25^\circ\text{C}$	38		A
$I_{D90}$	$T_c = 90^\circ\text{C}$	25		A
$dv/dt$	$V_{DS} < V_{DSS}$ ; $I_F \leq 50\text{A}$ ; $ di_F/dt  \leq 200\text{A}/\mu\text{s}$ $T_{VJ} = 150^\circ\text{C}$	6		V/ns
$E_{AS}$	$I_D = 10 \text{ A}$ ; $L = 36 \text{ mH}$ ; $T_c = 25^\circ\text{C}$	1.8		J
$E_{AR}$	$I_D = 20 \text{ A}$ ; $L = 5 \mu\text{H}$ ; $T_c = 25^\circ\text{C}$	1		mJ

Symbol	Conditions	Characteristic Values		
		( $T_{VJ} = 25^\circ\text{C}$ , unless otherwise specified)		
$R_{DSon}$	$V_{GS} = 10 \text{ V}$ ; $I_D = I_{D90}$			$70 \text{ m}\Omega$
$V_{GSth}$	$V_{DS} = 20 \text{ V}$ ; $I_D = 3 \text{ mA}$	3.5		$5.5 \text{ V}$
$I_{DSS}$	$V_{DS} = V_{DSS}$ ; $V_{GS} = 0 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		60	$25 \mu\text{A}$ $\mu\text{A}$
$I_{GSS}$	$V_{GS} = \pm 20 \text{ V}$ ; $V_{DS} = 0 \text{ V}$			$100 \text{ nA}$
$Q_g$ $Q_{gs}$ $Q_{gd}$	$V_{GS} = 10 \text{ V}$ ; $V_{DS} = 350 \text{ V}$ ; $I_D = 50 \text{ A}$		220 55 125	nC nC nC
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$	$V_{GS} = 10 \text{ V}$ ; $V_{DS} = 380 \text{ V}$ $I_D = 25 \text{ A}$ ; $R_G = 1.8 \Omega$		30 95 100 10	ns ns ns ns
$V_F$	(reverse conduction) $I_F = 20 \text{ A}$ ; $V_{GS} = 0 \text{ V}$	0.9	1.1	V
$R_{thJC}$	per MOSFET			$0.45 \text{ K/W}$

Data according to IEC 60747 refer to a single diode or transistor unless otherwise stated

<sup>1)</sup> CoolMOS is a trademark of Infineon Technologies AG.

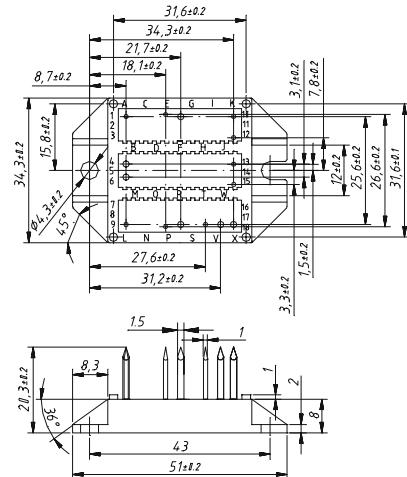
## Temperature Sensor NTC

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R <sub>25</sub>	T = 25°C	4.75	5.0	5.25 kΩ
B <sub>25/50</sub>			3375	K

## Module

Symbol	Conditions	Maximum Ratings	
$T_{VJ}$		-40...+150	°C
$T_{stg}$		-40...+125	°C
$V_{ISOL}$	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}; t = 1 \text{ s}$	3600	V~
$M_d$	mounting torque (M4)	1.5 - 2.0 14 - 18	Nm lb.in.
$a$	Max. allowable acceleration	50	m/s <sup>2</sup>

**Dimensions in mm (1 mm = 0.0394")**



Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$d_s$	Creepage distance on surface (Pin to heatsink)	11.2		mm
$d_A$	Strike distance in air (Pin to heatsink)	11.2		mm
<b>Weight</b>		24		g